

LM79XX

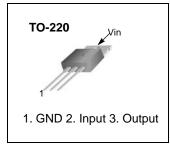
3-Terminal 1A Negative Voltage Regulator

Features

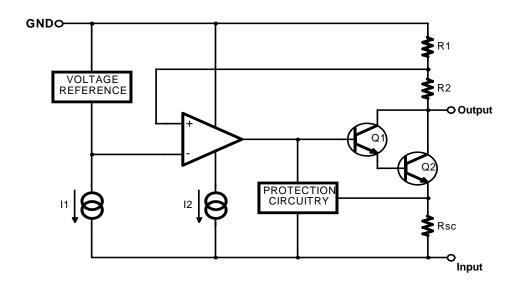
- Output Current in Excess of 1A
- Output Voltages of -5, -6, -8, -9, -10, -12, -15, -18 and -24V
- Internal Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area Compensation

Description

The LM79XX series of three terminal negative regulators are available in TO-220 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible.



Internal Block Digram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage	VI	-35	V
Thermal Resistance Junction-Case (Note1)	R _θ JC	5	°C/W
Thermal Resistance Junction-Air (Note1, 2)	RθJA	65	C/VV
Operating Temperature Range	TOPR	0 ~ +125	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

Note:

- 1. Thermal resistance test board Size: 76.2mm * 114.3mm * 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow

Electrical Characteristics (LM7905)

(V_I = -10V, I_O = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	
		T _J = +25°C		-4.8	-5.0	-5.2		
Output Voltage	Vo	$I_O = 5mA$ to 1A, $P_O \le 15W$ $V_I = -7V$ to $-20V$		-4.75	-5.0	-5.25	V	
Line Regulation (Note2)	4)/0	T _J = +25°C	VI = -7V to -25V		35	100	mV	
Line Regulation (Note3)	ΔVO	1J = +25 C	V _I = -8V to -12V	=.	8	50	IIIV	
Load Regulation (Note3)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5a$	A	-	10	100	mV	
Load Regulation (Notes)	ΔνΟ	T _J =+25°C I _O = 250mA to 750mA		-	3	50	IIIV	
Quiescent Current	IQ	T _J =+25°C		-	3	6	mA	
Quiescent Current Change	Alo	I _O = 5mA to 1A		-	0.05	0.5	mA	
Quiescent Current Change	ΔlQ	VI = -8V to -25V	to -25V		0.1	0.8	IIIA	
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	- 0.4	-	mV/°C	
Output Noise Voltage	VN	f = 10Hz to 100k T _A =+25°C	кНz	-	40	-	μV	
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB	
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V	
Short Circuit Current	Isc	T _J =+25°C, V _I = -35V		-	300	-	mA	
Peak Current	IPK	TJ =+25°C		-	2.2	-	Α	

Note

3. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7906) (Continued)

(VI = -11V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	
		Vo $T_{J} = +25^{\circ}C$ $I_{O} = 5mA \text{ to } 1A, P_{O} \le 15W$ $V_{I} = -9V \text{ to } -21V$		-5.75	-6	-6.25		
Output Voltage	Vo			-5.7	-6	-6.3	V	
Line Regulation (Note1)	4\/0	T _J = +25°C	VI = -8V to -25V	-	10	120	mV	
Line Regulation (Note1)	ΔVO	1J = +25 C	V _I = -9V to -13V	-	5	60	IIIV	
Load Regulation (Note1)	ΔVΩ	T _J = +25°C I _O = 5mA to 1.5A T _J =+25°C I _O = 250mA to 750mA		-	10	120	mV	
Load Regulation (Note I)				-	3	60	IIIV	
Quiescent Current	IQ	TJ =+25°C		-	3	6	mA	
Quincant Current Change	Alo.	$I_O = 5mA$ to $1A$		-	0.05	0.5	mA	
Quiescent Current Change	ΔlQ	VI = -8V to -25V		-	0.1	1.3	IIIA	
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.5	-	mV/°C	
Output Noise Voltage	VN	f = 10Hz to 100k T _A =+25°C	Hz	-	130	-	μV	
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB	
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V	
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA	
Peak Current	IPK	TJ = +25°C		-	2.2	-	А	

Note

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7908) (Continued)

(VI = -14V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		-7.7	-8	-8.3	
Output Voltage	Vo	IO = 5mA to 1A, PO ≤ 15W VI = -10V to -23V		-7.6	-8	-8.4	V
Line Regulation (Note1)	ΔVο	T 125°C	V _I = -10.5V to -25V	-	10	160	mV
Line Regulation (Note1)	ΔνΟ	TJ = +25°C	V _I = -11V to -17V	-	5	80	IIIV
Load Regulation (Note1)	۸۷۵	ΔV_{O} T _J = +25°C I _O = 5mA to 1.5A T _J =+25°C I _O = 250mA to 750mA		-	12	160	mV
Load (Note I)	ΔνΟ			-	4	80	IIIV
Quiescent Current	IQ	T _J =+25°C		-	3	6	mA
Quioccont Current Change	Alo	I _O = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	VI = -10.5V to -25V		-	0.1	1	ША
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100 T _A =+25°C)kHz	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	А

Note

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7909) (Continued)

(VI = -15V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C	T _J = +25°C		-9.0	-9.3	
Output Voltage		VO $IO = 5mA \text{ to } 1A, PO \le 15W$ VI = -1.5V to -23V		-8.6	-9.0	-9.4	V
Line Regulation (Note1)	ΔVο	T _J = +25°C	VI = -11.5V to -26V	-	10	180	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V _I = -12V to -18V	-	5	90	IIIV
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$	Ą	-	12	180	mV
Load Regulation (Note I)	$ T = +25^{\circ}C$	T _J = +25°C			4	90	IIIV
Quiescent Current	IQ	T _J = +25°C		-	3	6	mA
Quincant Current Change	Alo	Io = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	VI = -11.5V to -26V		-	0.1	1	IIIA
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	Hz	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7910) (Continued)

(VI = -17V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	
		T _J = +25°C	T _J = +25°C		-10	-10.4		
Output Voltage	Vo	IO = 5mA to 1A, Pd ≤ 15W VI = -12V to -28		-9.5	-10	-10.5	V	
Line Regulation (Note1)	ΔVο	T _J = +25°C	V _I = -12.5V to -28V	-	12	200	mV	
Line Regulation (Note1)	ΔνΟ	1J = +25 C	V _I = -14V to -20V	-	6	100	1117	
Load Regulation (Note1)	ΔVο	T _J = +25°C I _O = 5mA to 1.5A	4	-	12	200	mV	
Load Regulation (Note I)	TJ	T _J = +25°C I _O = 250mA to 750mA		$TJ = +25^{\circ}C$	-	4	100	IIIV
Quiescent Current	IQ	T _J = +25°C		-	3	6	mA	
Ouissant Current Change	Alo	IO = 5mA to 1A		-	0.05	0.5	A	
Quiescent Current Change	ΔlQ	V _I = -12.5V to -2	8V	-	0.1	mA		
Temperature Coefficient of VO	ΔVο/ΔΤ	IO = 5mA		•	-1	-	mV/°C	
Output Noise Voltage	VN	10Hz ≤ f ≤ 100kH T _A =+25°C	Ηz	-	280	-	μV	
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB	
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V	
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA	
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α	

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7912) (Continued)

(VI = -19V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		-11.5	-12	-12.5	
Output Voltage	Vo	IO = 5mA to 1A, VI = -15.5V to -2		-11.4	-12	-12.6	V
Line Regulation (Note1)	41/0	T _J = +25°C	VI = -14.5V to -30V	-	12	240	mV
Line Regulation (Note1)	ΔVO	1J = +25°C	V _I = -16V to -22V	-	6	120	IIIV
Load Regulation (Note1)	11/0	T _J = +25°C I _O = 5mA to 1.5A	4	-	12	240	mV
Load Regulation (Note1)	ΔVΟ	TJ = +25°C IO = 250mA to 750mA		-	4	120	IIIV
Quiescent Current	IQ	T _J = +25°C		-	3	6	mA
Quioscont Current Change	l ΔlO ———	$I_O = 5mA$ to 1A		-	0.05	0.5	mA
Quiescent Current Change		V _I = -14.5V to -30V	-	0.1	1	IIIA	
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	Hz	-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7915) (Continued)

(VI = -23V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		-14.4	-15	-15.6	
Output Voltage	Vo		IO = 5mA to 1A, PO ≤ 15W VI = -18V to -30V		-15	-15.75	V
Line Regulation (Note1)	ΔVο	TJ = +25°C	V _I = -17.5V to -30V	-	12	300	mV
Line Regulation (Note1)	ΔνΟ	1J = +25 C	V _I = -20V to -26V	-	6	150	IIIV
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5$	A	-	12	300	mV
Load Regulation (Note I)	Δ۷Ο	TJ = +25°C IO = 250mA to 750mA		-	4	150	
Quiescent Current	IQ	T _J = +25°C		-	3	6	mA
Quioscont Current Change	Alo.	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	$V_{I} = -17.5V \text{ to } -30V$	-	0.1	1	ША	
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A =+25°C	кНz	-	250	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (LM7918) (Continued)

(VI = -27V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		-17.3	-18	-18.7	
Output Voltage	Vo	IO = 5mA to 1A, PO ≤ 15W VI = -22.5V to -33V		-17.1	-18	-18.9	V
Line Regulation (Note1)	ΔVο	T _J = +25°C	VI = -21V to -33V	-	15	360	mV
Line Regulation (Note I)	ΔνΟ	1J = +25 C	V _I = -24V to -30V	-	8	180	IIIV
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$	Ą	-	15	360	mV
Load (Note I)	ΔνΟ	T _J = +25°C I _O = 250mA to 750mA		-	5	180	IIIV
Quiescent Current	IQ	T _J = +25°C		-	3	6	mA
Quioccont Current Change	Alo	IO = 5mA to 1A		-	0.05	0.5	mA
Quiescent Current Change	ΔIQ	ΔIQ $V_I = -21V \text{ to } -33V$		-	0.1	1	ША
Temperature Coefficient of VD	ΔVo/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	Hz	-	300	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

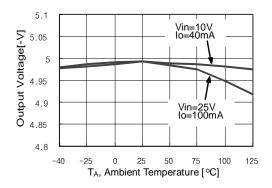
Electrical Characteristics (LM7924) (Continued)

(VI = -33V, IO = 500mA, 0° C \leq TJ \leq +125 $^{\circ}$ C, CI =2.2 μ F, CO =1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	
		T _J = +25°C		-23	-24	-25		
Output Voltage	Vo		IO = 5mA to 1A, PO ≤ 15W VI = -27V to -38V		-24	-25.2	V	
Line Regulation (Note1)	41/0	T _J = +25°C	VI = -27V to -38V	-	15	480	mV	
Line Regulation (Note1)	ΔVO	1J = +25°C	V _I = -30V to -36V	-	8	180	IIIV	
Load Regulation (Note1)	ΔVο	$T_J = +25^{\circ}C$ $I_O = 5mA \text{ to } 1.5a$	A	-	15	480	mV	
Load Regulation (Note 1)	Δ۷Ο	T _J = +25°C I _O = 250mA to 750mA		T _J = +25°C	-	5	240	IIIV
Quiescent Current	lQ	T _J = +25°C		-	3	6	mA	
Quiagont Current Change	Alo.	IO = 5mA to 1A		-	0.05	0.5	mA	
Quiescent Current Change	ΔlQ	$V_I = -27V \text{ to } -38$	V	-	0.1	1		
Temperature Coefficient of VD	ΔVο/ΔΤ	IO = 5mA		-	-1	-	mV/°C	
Output Noise Voltage	VN	f = 10Hz to 100k T _A = +25°C	кНz	-	400	-	μV	
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB	
Dropout Voltage	VD	T _J = +25°C I _O = 1A		-	2	-	V	
Short Circuit Current	Isc	T _J = +25°C, V _I = -35V		-	300	-	mA	
Peak Current	IPK	TJ = +25°C		-	2.2	-	А	

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Performance Characteristics



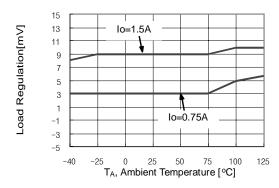
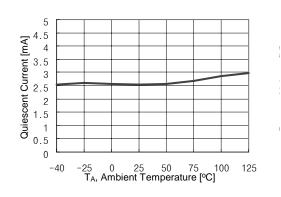


Figure 1. Output Voltage

Figure 2. Load Regulation



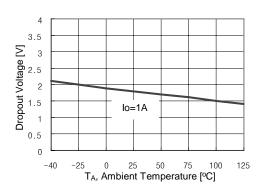


Figure 3. Quiescent Current

Figure 4. Dropout Voltage

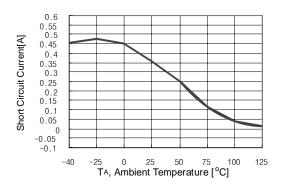


Figure 5. Short Circuit Current

Typical Applications

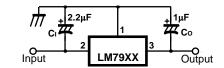


Figure 6. Negative Fixed output regulator

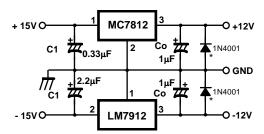


Figure 7. Split power supply (\pm 12V/1A)

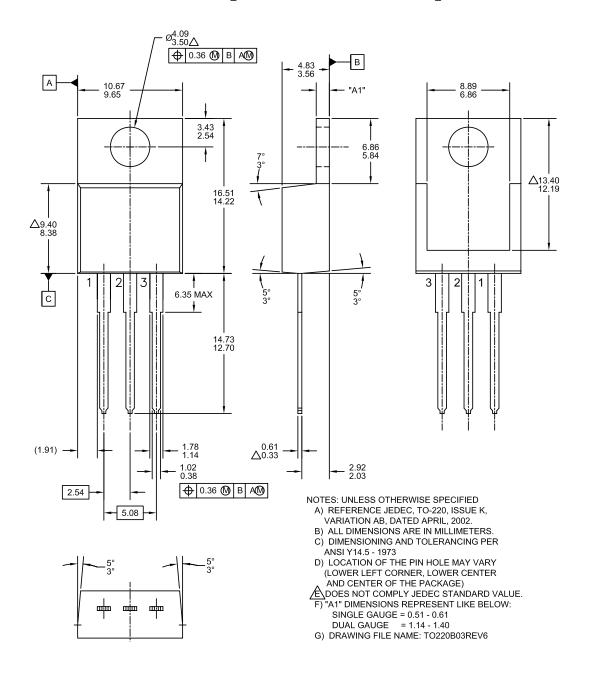
- (1) To specify an output voltage, substitute voltage value for "XX"
- (2) Required for stability. For value given, capacitor must be solid tantalum. If aluminium electronics are used, at least ten times value shown should be selected. C_I is required if regulator is located an appreciable distance from power supply filter.
- (3) To improve transient response. If large capacitors are used, a high current diode from input to output (1N400l or similar) should be introduced to protect the device from momentary input short circuit.

Mechanical Dimensions

Package

Dimensions in millimeters

TO-220 [SINGLE GAUGE]



Ordering Information

Product Number	Output Voltage Tolerance	Package	Operating Temperature
LM7905CT			
LM7906CT			
LM7908CT			
LM7909CT			
LM7910CT	±4%	TO-220	0 ~ +125°C
LM7912CT			
LM7915CT			
LM7918CT			
LM7924CT			

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- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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